

Precision Low-Voltage, Low-Glitch CMOS Analog Switches

DESCRIPTION

Using BiCMOS wafer fabrication technology allows the DG9421, DG9422 to operate on single and dual supplies.

Designed for optimal performance at single 5 V and dual ± 5 V, the DG9421, DG9422 combine low and flat on-resistance ($3\ \Omega$), fast speed ($t_{ON} = 38\text{ ns}$) and is well suited for applications where signal switching accuracy, low noise and low distortion is critical.

The DG9421 and DG9422 respond to opposite control logic as shown in the Truth Table.

FEATURES

- 2.7- thru 12 V single supply or ± 2.7 - thru ± 6 -dual supply
- Low on-resistance - $R_{DS(on)}$: $2.0\ \Omega$ at 12 V
- Fast switching - t_{ON} : 28 ns
- - t_{OFF} : 22 ns
- TTL and low voltage logic
- Low leakage: 10 pA (typ.)
- > 2000 V ESD protection



RoHS*
COMPLIANT

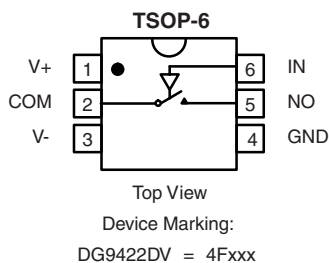
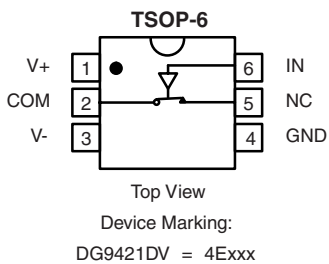
BENEFITS

- High accuracy
- High speed, low glitch
- Single and dual supply capability
- Low R_{ON} in small TSOP package
- Low leakage
- Low power consumption

APPLICATIONS

- Automatic test equipment
- Data acquisition
- XDSL and DSLAM
- PBX systems
- Reed relay replacement
- Audio and video signal routing

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION



TRUTH TABLE

Logic	DG9421	DG9422
0	ON	OFF
1	OFF	ON

Logic "0" $\leq 0.8\text{ V}$

Logic "1" $\geq 2.4\text{ V}$

Switches Shown for Logic "0" Input

ORDERING INFORMATION

Temp. Range	Package	Part Number
- 40 °C to 85 °C	6/Pin TSOP	DG9421DV-T1
		DG9421DV-T1-E3
		DG9422DV-T1
		DG9422DV-T1-E3

* Pb containing terminations are not RoHS compliant, exemptions may apply

ABSOLUTE MAXIMUM RATINGS

Parameter	Limit	Unit
V+ to V-	- 0.3 to 13	V
GND to V-	7	
V _{IN} ^a , V _S , V _D	- 0.3 to (V+ + 0.3) or 50 mA, whichever occurs first	V/mA
Continuous Current (Any Terminal)	50	mA
Peak Current, S or D (Pulsed at 1 ms, 10 % Duty Cycle)	100	
Storage Temperature	- 65 to 150	°C
Power Dissipation (Packages) ^b	6-Pin TSOP ^c	mW

Notes:

a. Signals on S_X, D_X, or I_{NX} exceeding V+ or V- will be clamped by internal diodes. Limit forward diode current to maximum current ratings.

b. All leads welded or soldered to PC board.

c. Derate 7 mW/°C above 25 °C.

SPECIFICATIONS^a Single Supply 12 V

Parameter	Symbol	Test Conditions Unless Otherwise Specified V ₊ = 12 V, V ₋ = 0 V, V _{IN} = 2.4 V, 0.8 V ^f	Temp. ^b	Limits - 40 °C to 85°C			Unit
				Min. ^d	Typ. ^c	Max. ^d	
Analog Switch							
Analog Signal Range ^a	V _{ANALOG}		Full	0		12	V
Drain-Source On-Resistance	R _{DS(on)}	V ₊ = 10.8 V, V ₋ = 0 V, I _S = 5 mA, V _D = 2/9 V	Room Full		2.0	3 3.4	Ω
Switch Off Leakage Current	I _{S(off)}	V _D = 1/11 V, V _S = 11/1 V	Room Full	- 1 - 10		1 10	nA
	I _{D(off)}		Room Full	- 1 - 10		1 10	
Channel-On Leakage Current	I _{D(on)}	V _S = V _D = 11/1 V	Room Full	- 1 - 10		1 10	
Digital Control							
Input Current, V _{IN} Low	I _{IL}	V _{IN} Under Test = 0.8 V	Full	- 1	0.02	1	μA
Input Current, V _{IN} High	I _{IH}	V _{IN} Under Test = 2.4 V	Full	- 1	0.02	1	
Dynamic Characteristics							
Turn-On Time ^e	t _{ON}	R _L = 300 Ω, C _L = 35 pF, V _S = 5 V See Figure 2	Room Full		20	45 49	ns
Turn-Off Time ^e	t _{OFF}		Room Full		25	47 59	
Charge Injection ^e	Q	V _g = 0 V, R _g = 0 Ω, C _L = 1 nF	Room		43		pC
Off-Isolation ^e	OIRR	R _L = 50 Ω, C _L = 5 pF, f = 1 MHz	Room		- 60		dB
Source Off Capacitance ^e	C _{S(off)}	f = 1 MHz	Room		31		pF
Drain Off Capacitance ^e	C _{D(off)}		Room		30		
Channel On Capacitance ^e	C _{D(on)}		Room		71		
Power Supplies							
Positive Supply Current	I ₊	V _{IN} = 0 or 12 V	Room Full		0.02	1 5	μA
Negative Supply Current	I ₋		Room Full	- 1 - 5	- 0.002		
Ground Current	I _{GND}		Room Full	- 1 - 5	- 0.002		



SPECIFICATIONS ^a Dual Supply ± 5 V							
Parameter	Symbol	Test Conditions Unless Otherwise Specified $V_+ = 5$ V, $V_- = -5$ V, $V_{IN} = 2.4$ V, 0.8 V ^f	Temp. ^b	Limits - 40 °C to 85 °C			Unit
				Min. ^d	Typ. ^c	Max. ^d	
Analog Switch							
Analog Signal Range ^e	V_{ANALOG}		Full	- 5		5	V
Drain-Source On-Resistance	$R_{DS(on)}$	$V_+ = 5$ V, $V_- = -5$ V $I_S = 5$ mA, $V_D = \pm 3.5$ V	Room Full		2.2	3.2 3.6	Ω
Switch Off Leakage Current ^g	$I_{S(off)}$	$V_+ = 5.5$ V, $V_- = -5.5$ V $V_D = \pm 4.5$ V, $V_S = \pm 4.5$ V	Room Full	- 1 - 10		1 10	nA
	$I_{D(off)}$		Room Full	- 1 - 10		1 10	
Channel-On Leakage Current ^g	$I_{D(on)}$	$V_+ = 5.5$ V, $V_- = -5.5$ V $V_S = V_D = \pm 4.5$ V	Room Full	- 1 - 10		1 10	
Digital Control							
Input Current, V_{IN} Low ^e	I_{IL}	V_{IN} Under Test = 0.8 V	Full	- 1	0.02	1	μ A
Input Current, V_{IN} High ^e	I_{IH}	V_{IN} Under Test = 2.4 V	Full	- 1	0.02	1	
Dynamic Characteristics							
Turn-On Time	t_{ON}	$R_L = 300 \Omega$, $C_L = 35$ pF, $V_S = \pm 3.5$ V See Figure 2	Room Full		38	63 68	ns
Turn-Off Time	t_{OFF}		Room Full		45	83 97	
Charge Injection ^e	Q	$V_g = 0$ V, $R_g = 0 \Omega$, $C_L = 1$ nF	Room		207		pC
Off-Isolation ^e	OIRR	$R_L = 50 \Omega$, $C_L = 5$ pF , $f = 1$ MHz	Room		- 57		dB
Source Off Capacitance ^e	$C_{S(off)}$	$f = 1$ MHz	Room		32		pF
Drain Off Capacitance ^e	$C_{D(off)}$		Room		31		
Channel On Capacitance ^e	$C_{D(on)}$		Room		71		
Power Supplies							
Positive Supply Current ^e	I_+	$V_{IN} = 0$ or 5 V	Room Full		0.03	1 5	μ A
Negative Supply Current ^e	I_-		Room Full	- 1 - 5	- 0.002		
Ground Current ^e	I_{GND}		Room Full	- 1 - 5	- 0.002		

SPECIFICATIONS ^a Single Supply 5 V							
Parameter	Symbol	Test Conditions Unless Otherwise Specified V+ = 5 V, V- = 0 V, V _{IN} = 2.4 V, 0.8 V ^f	Temp. ^b	Limits - 40 °C to 85 °C			Unit
				Min. ^d	Typ. ^c	Max. ^d	
Analog Switch							
Analog Signal Range ^e	V _{ANALOG}		Full	0		5	V
Drain-Source On-Resistance	R _{DS(on)}	V+ = 4.5 V, I _S = 5 mA, V _D = 1 V, 3.5 V	Room Full		3.6	6.0 6.6	Ω
Dynamic Characteristics							
Turn-On Time ^e	t _{ON}	R _L = 300 Ω, C _L = 35 pF, V _S = 3.5 V, See Figure 2	Room Hot		43	67 74	ns
Turn-Off Time ^e	t _{OFF}		Room Hot		30	67 80	
Charge Injection ^e	Q	V _g = 0 V, R _g = 0 Ω, C _L = 1 nF	Room		25		pC
Power Supplies							
Positive Supply Current ^e	I+	V _{IN} = 0 or 5 V	Room Hot		0.02	1 5	μA
Negative Supply Current ^e	I-		Room Hot	- 1 - 5	- 0.002		
Ground Current ^e	I _{GND}		Room Hot	- 1 - 5	- 0.002		



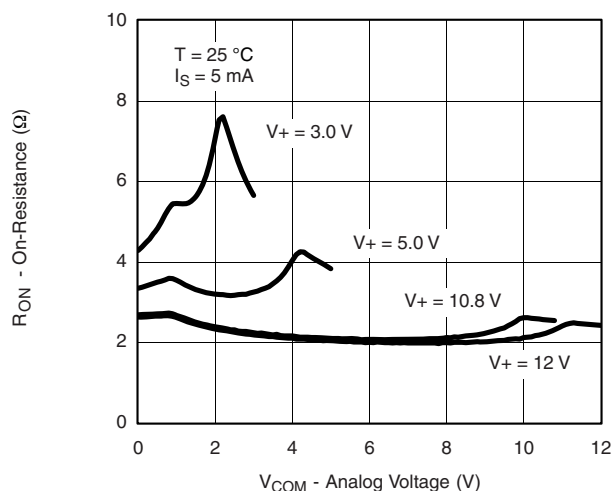
SPECIFICATIONS ^a Single Supply 3 V							
Parameter	Symbol	Test Conditions Unless Otherwise Specified V ₊ = 3 V, V ₋ = 0 V, V _{IN} = 0.4 V ^f	Temp ^b	Limits - 40 °C to 85 °C			Unit
				Min. ^d	Typ. ^c	Max. ^d	
Analog Switch							
Analog Signal Range ^e	V _{ANALOG}		Full	0		3	V
Drain-Source On-Resistance	R _{DS(on)}	V ₊ = 2.7 V, V ₋ = 0 V I _S = 5 mA, V _D = 0.5, 2.2 V	Room Full		7.3	8.8 10.1	Ω
Switch Off Leakage Current ^g	I _{S(off)}	V ₊ = 3.3 V, V ₋ = 0 V V _S = 1, 2 V, V _D = 2, 1 V	Room Full	- 1 - 10		1 10	nA
	I _{D(off)}		Room Full	- 1 - 10		1 10	
Channel-On Leakage Current ^g	I _{D(on)}	V ₊ = 3.3 V, V ₋ = 0 V V _D = V _S = 1, 2 V	Room Full	- 1 - 10		1 10	
Digital Control							
Input Current, V _{IN} Low ^e	I _{IL}	V _{IN} Under Test = 0.4 V	Full	- 1	0.02	1	μA
Input Current, V _{IN} High ^e	I _{IH}	V _{IN} Under Test = 2.4 V	Full	- 1	0.02	1	
Dynamic Characteristics							
Turn-On Time	t _{ON}	R _L = 300 Ω, C _L = 35 pF, V _S = 1.5 V See Figure 2	Room Full		90	110 125	ns
Turn-Off Time	t _{OFF}		Room Full		32	84 99	
Charge Injection ^e	Q	V _g = 0 V, R _g = 0 Ω, C _L = 1 nF	Room		31		pC
Off-Isolation ^e	OIRR	R _L = 50 Ω, C _L = 5 pF, f = 1 MHz	Room		- 60		dB
Source Off Capacitance ^e	C _{S(off)}	f = 1 MHz	Room		35		pF
Drain Off Capacitance ^e	C _{D(off)}		Room		34		
Channel On Capacitance ^e	C _{D(on)}		Room		77		

Notes:

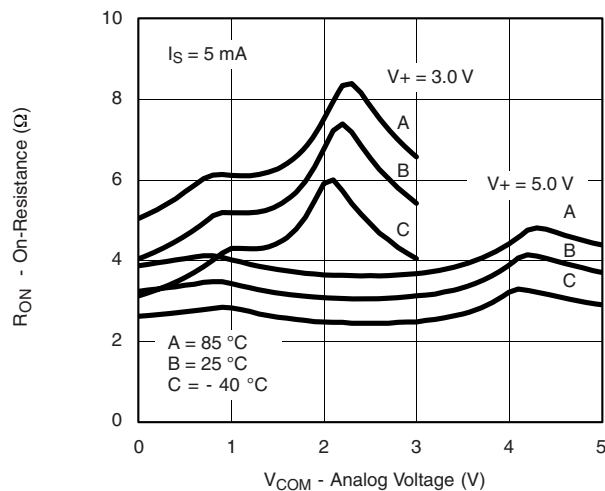
- Refer to PROCESS OPTION FLOWCHART.
- Room = 25 °C, Full = as determined by the operating temperature suffix.
- Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
- The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
- Guaranteed by design, not subject to production test.
- V_{IN} = input voltage to perform proper function.
- Leakage parameters are guaranteed by worst case test conditions and not subject to test.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

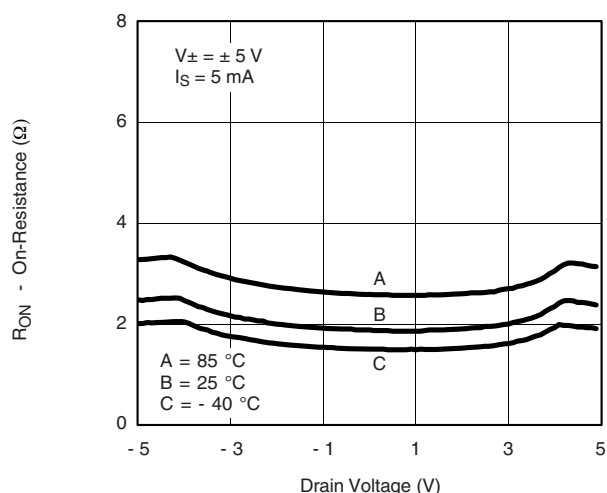
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



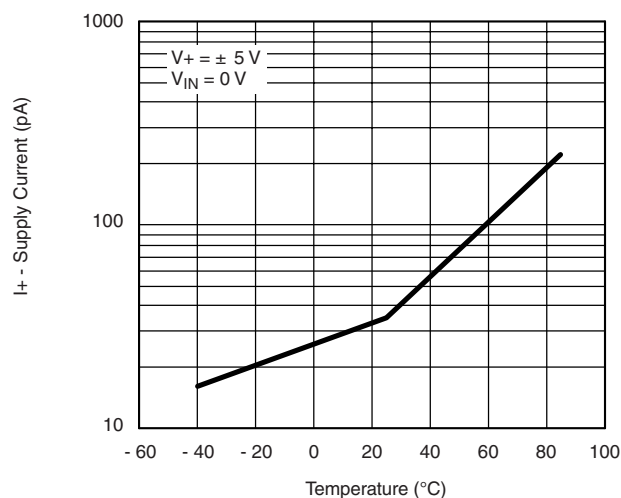
R_{ON} vs. V_{COM} and Supply Voltage



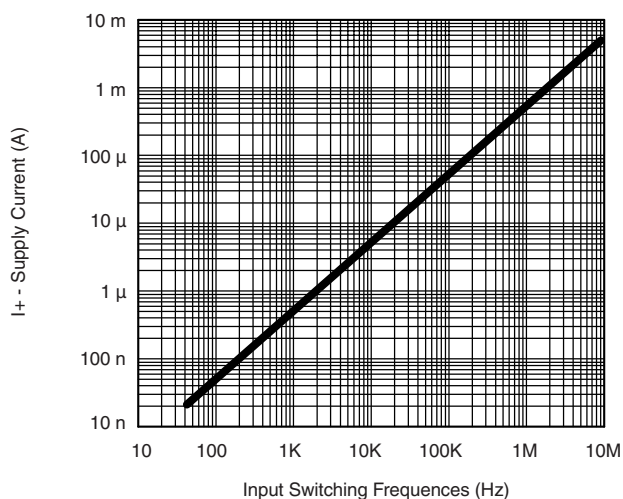
R_{ON} vs. Analog Voltage and Temperature



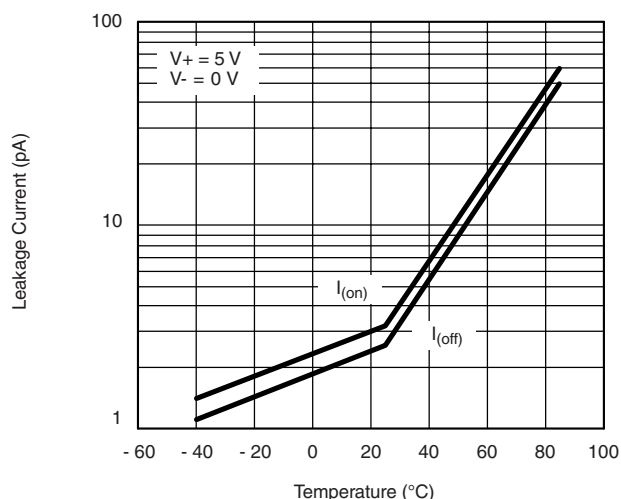
R_{ON} vs. Analog Voltage and Temperature



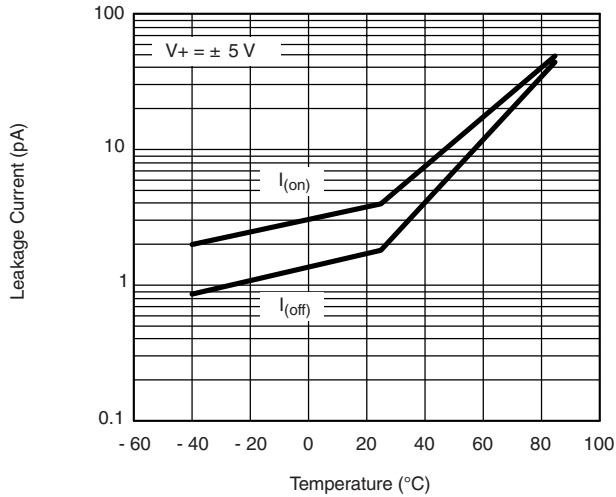
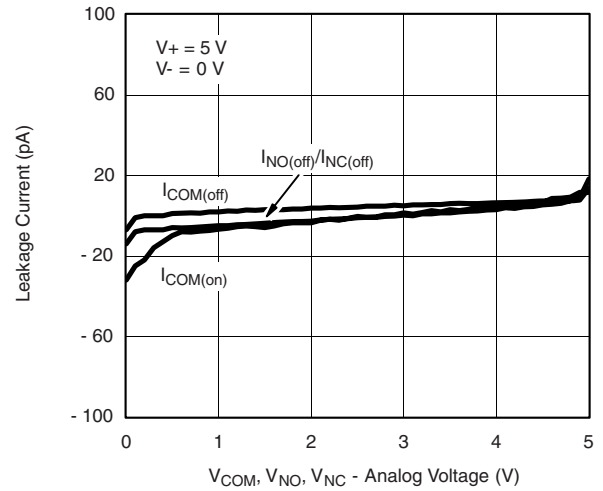
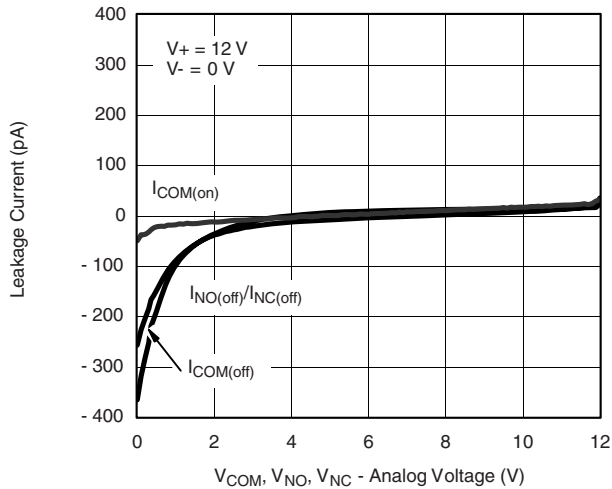
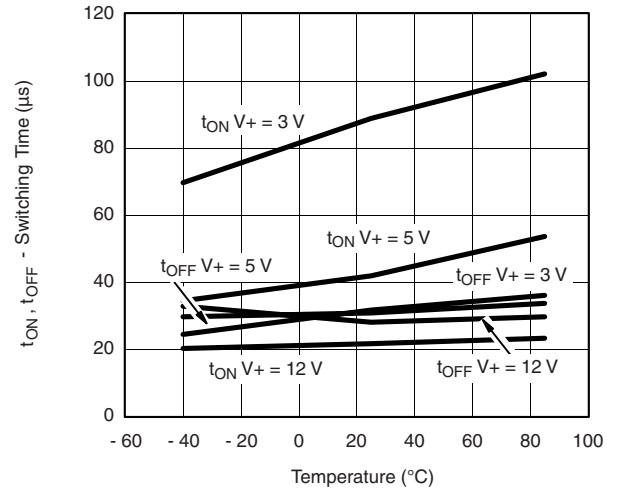
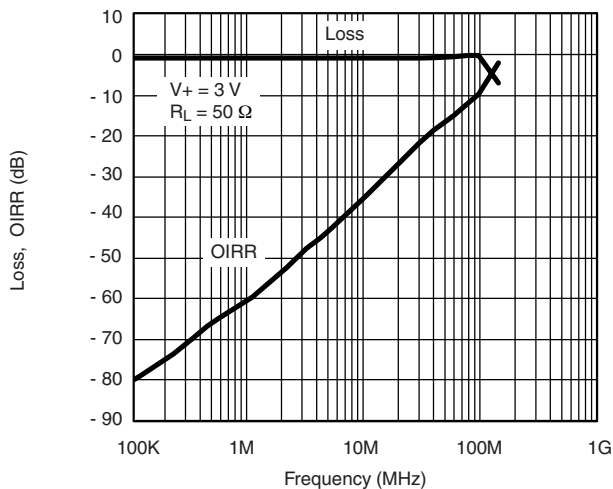
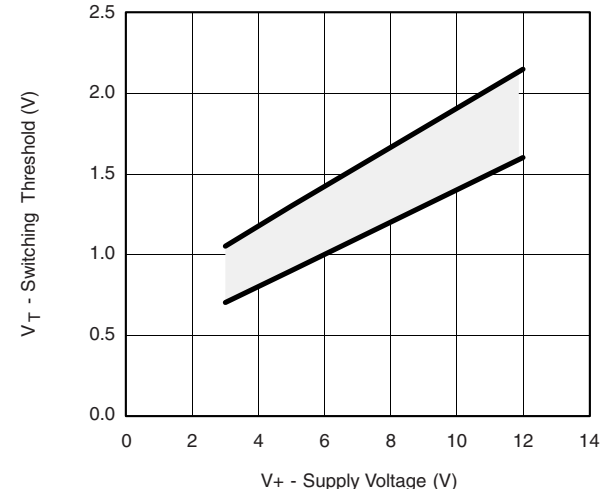
Supply Current vs. Temperature



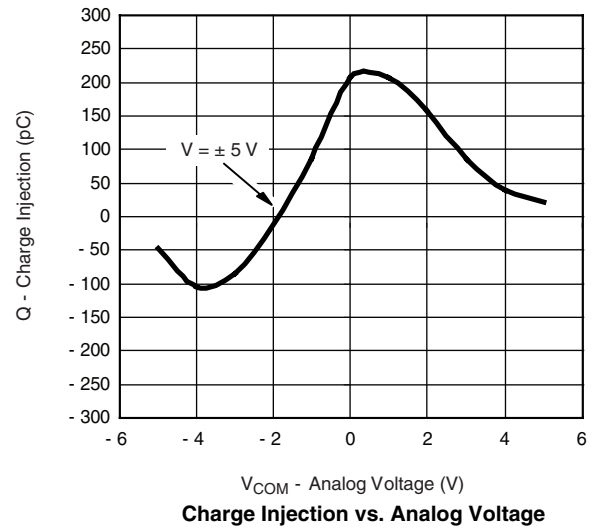
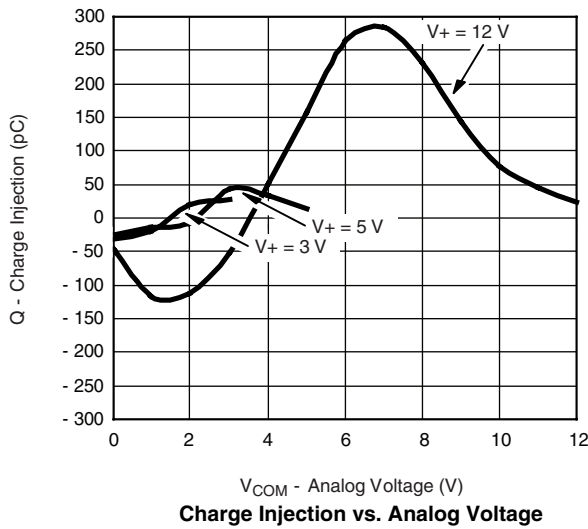
Supply Current vs. Input Switching Frequency



Leakage Current vs. Temperature

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

Leakage Current vs. Temperature

Leakage vs. Analog Voltage

Leakage vs. Analog Voltage

Switching Time vs. Temperature and Supply Voltage (DG9421)

Insertion Loss, Off Isolation vs. Frequency

Switching Threshold vs. Supply Voltage

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



SCHEMATIC DIAGRAM Typical Channel

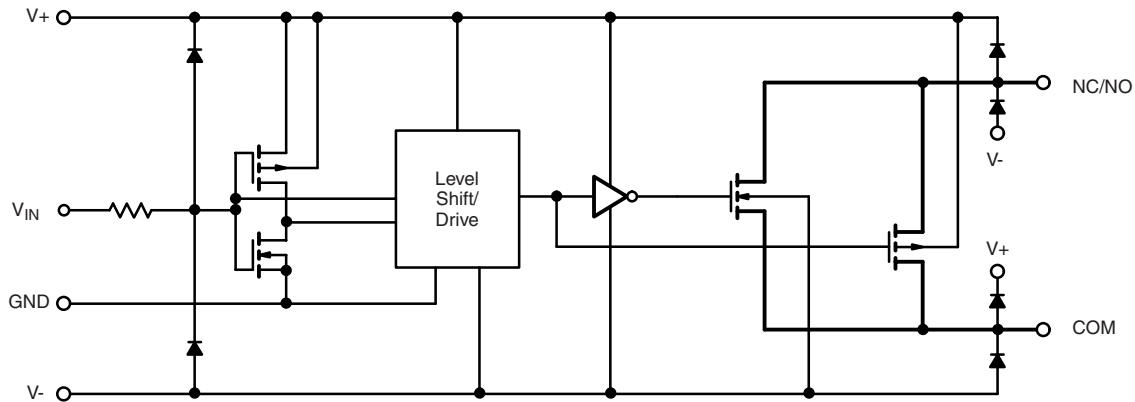
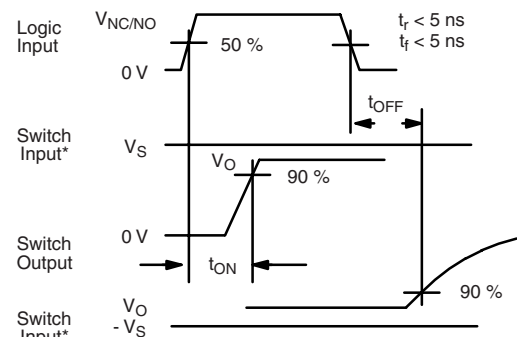
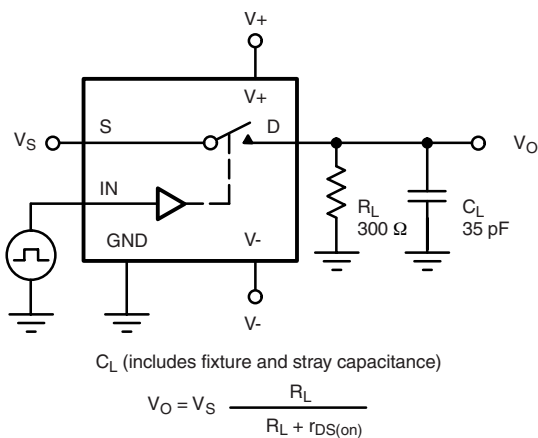


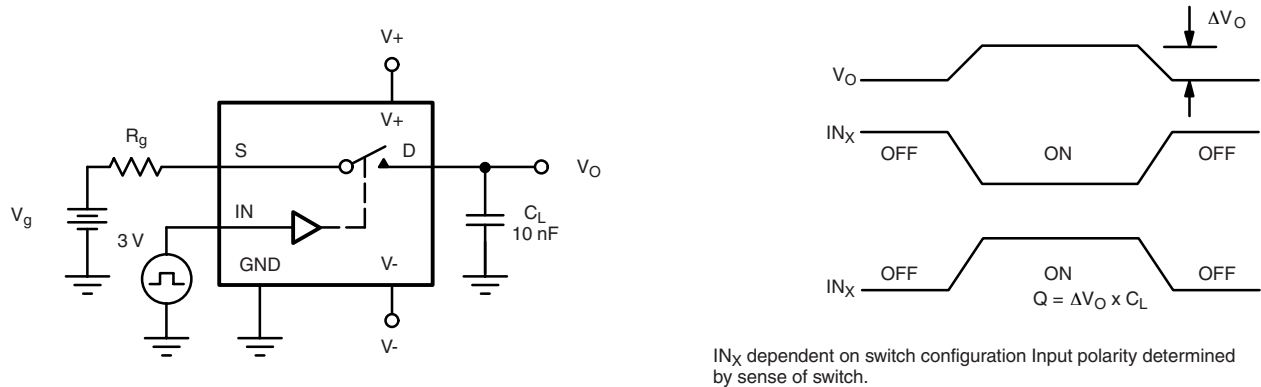
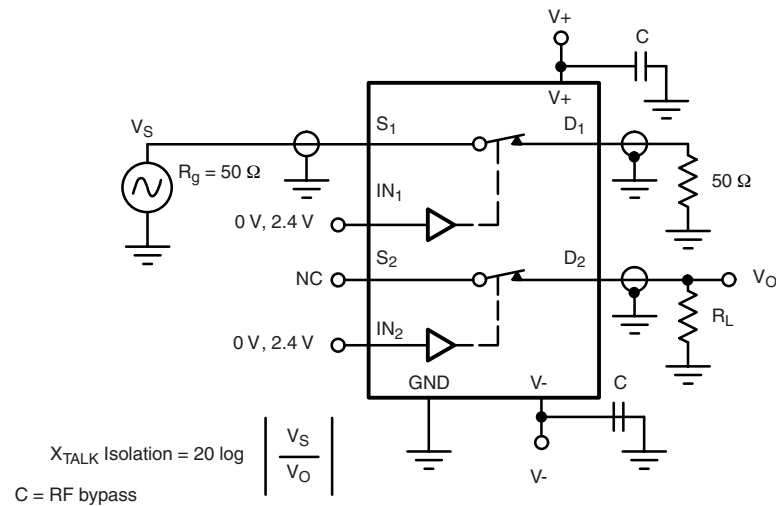
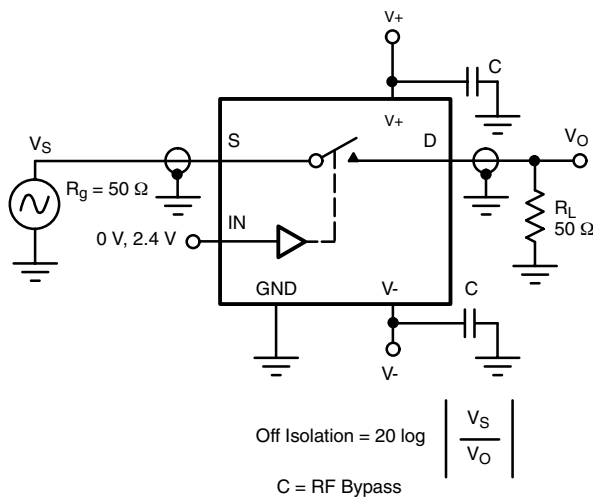
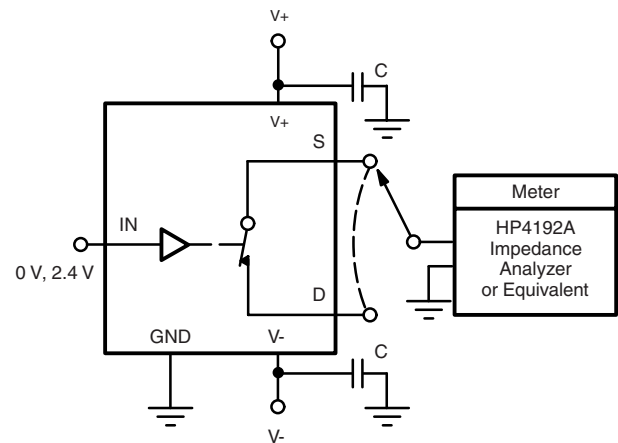
Figure 1.

TEST CIRCUITS



Note: * Logic input waveform is inverted for switches that have the opposite logic sense control

Figure 2. Switching Time

TEST CIRCUITS

Figure 3. Charge Injection

Figure 4. Crosstalk

Figure 5. Off Isolation

Figure 6. Source/Drain Capacitances

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